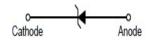


## 1 W DO-41 ZENER DIODES

1N4727A - 1N4761A





DO-41 Axial Glass Package RoHS compliant

This product is available in AEC-Q101 Compliant also

NOTE: For AEC-Q101 compliant products, please use suffix -AQ in the part number while ordering **General Description** 

Standard zener voltage tolerance is  $\pm 10\%$  With suffix "A" zener voltage tolerance is  $\pm 5\%$  and with suffix "B" zener voltage tolerance is  $\pm 2\%$ . The Glass Passivated Chips are Hermetically Sealed with Double Studs, Providing Excellent Stability and reliability.

#### **APPLICATIONS**

In stabilizing and clipping circuits with higher power rating

## ABSOLUTE MAXIMUM RATINGS ( $T_a = 25$ °C)

Parameter	ol	Value	Unit
Power Dissipation	P <sub>TOT</sub> (1)	1	W
Junction Temperature	TJ	200	°C
Storage Temperature Range	T <sub>STG</sub>	- 65 to +200	°C

Note: 1. Valid provided that leads at a distance of 8 mm from case are kept at ambient

## Thermal Characteristics at T<sub>a</sub> = 25 °C

Parameter	Symb	Value	Unit
Thermal Resistance Junction to			
Ambient Air	$R_{\theta JA}$	170 <sup>(1)</sup>	K/mW
Forward Voltage at IF = 200 mA	V <sub>F</sub>	1.2	V

Note: 1. Valid provided that leads at a distance of 8 mm from case are kept at ambient



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ELECTRICAL CHARACTERISTICS at T<sub>a</sub> = 25 °C

Dowt	Zener \	√oltage R	ange (3)	Dynami	c resista	nce (1)	Reve Curre		Maximum Surge	Maximum Regulator	Temp.
Part Number	$V_{Znom}$	V <sub>ZT</sub>	at I <sub>ZT</sub>	<b>Z</b> zt	<b>Z</b> zk	at Izк	<b>I</b> R	at V <sub>R</sub>	Current (4)	Current (2)	at I <sub>ZM</sub> (mA)
Number	(V)	(V)	(mA)	Max. (Ω)	Max. (Ω)	(mA)	Max. (μA)	Max (µA)	Izsм (mA)	Izм (mA)	%/ °C
1N4727A	3	2.85- 3.15	83	10	400	1	150	1	1375	275	-0.08 to - 0.05
1N4728A	3.3	3.13- 3.47	76	10	400	1	150	1	1375	275	-0.08 to - 0.05
1N4729A	3.6	3.42- 3.78	69	10	400	1	100	1	1260	252	-0.08 to -0.05
1N4730A	3.9	3.7-4.1	64	9	400	1	100	1	1190	234	-0.07 to -0.02
1N4731A	4.3	4.08- 4.52	58	9	400	1	50	1	1070	217	-0.07 to -0.01
1N4732A	4.7	4.46- 4.94	53	8	500	1	10	1	970	193	-0.03 to +0.04
1N4733A	5.1	4.84- 5.36	49	7	550	1	10	1	890	178	-0.01 to +0.04
1N4734A	5.6	5.32- 5.88	45	5	600	1	10	2	810	162	0.10 to +0.045
1N4735A	6.2	5.89- 6.51	41	2	700	1	10	3	730	146	+0.01 to +0.055
1N4736A	6.8	6.46- 7.14	37	3.5	700	1	10	4	660	133	+0.015 to +0.06
1N4737A	7.5	7.12- 7.88	34	4	700	0.5	10	5	605	121	+0.02 to +0.065
1N4738A	8.2	7.79- 8.61	31	4.5	700	0.5	10	6	550	110	0.03 to 0.07
1N4739A	9.1	8.64- 9.56	28	5	700	0.5	10	7	500	100	0.035 to 0.075
1N4740A	10	9.5-10.5	25	7	700	0.25	10	7.6	454	91	0.04 to 0.08
1N4741A	11	10.45- 11.55	23	8	700	0.25	5	8.4	414	83	0.045 to 0.08
1N4742A	12	11.4- 12.6	21	9	700	0.25	5	9.1	380	76	0.045 to 0.085
1N4743A	13	12.35- 13.65	19	10	700	0.25	5	9.9	344	69	0.05 to 0.085
1N4744A	15	14.25- 15.75	17	14	700	0.25	5	11.4	304	61	0.055 to 0.09
1N4745A	16	15.2- 16.8	15.5	16	700	0.25	5	12.2	285	57	0.055 to 0.09
1N4746A	18	17.1- 18.9	14	20	750	0.25	5	13.7	250	50	0.06 to 0.09
1N4747A	20	19-21	12.5	22	750	0.25	5	15.2	225	45	0.06 to 0.09
1N4748A	22	20.9- 23.1	11.5	23	750	0.25	5	16.7	205	41	0.06 to 0.095
1N4749A	24	22.8- 25.2	10.5	25	750	0.25	5	18.2	190	38	0.06 to 0.095
1N4750A	27	25.65- 28.35	9.5	35	750	0.25	5	20.6	170	34	0.06 to 0.095



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## **ELECTRICAL CHARACTERISTICS at T<sub>a</sub> = 25 °C**

	Ze	ener Volta	ge Rang	e <sup>(3)</sup>	Dyna resista		Reve Curre		Maximum Surge	Maximum Regulator	Temp.
Part Number	$V_{Znom}$	V <sub>ZT</sub>	at I <sub>zT</sub>	<b>Z</b> zT	<b>Z</b> zk	at Izĸ	lR	at V <sub>R</sub>	Current (4)	Current (2)	at I <sub>ZM</sub> (mA)
	(V)	(V)	(mA)	Max. (Ω)	Max. (Ω)	(mA)	Max. (μΑ)	Max (µA)	Izsм (mA)	Izм (mA)	%/ °C
1N4751A	30	28.5- 31.5	8.5	40	1000	0.25	5	22.8	150	30	0.06 to 0.095
1N4752A	33	31.35 34.65	7.5	45	1000	0.25	5	25.1	135	27	0.06 to 0.095
1N4753A	36	34.2- 37.8	7	50	1000	0.25	5	27.4	125	25	0.06 to 0.095
1N4754A	39	37.05- 40.95	6.5	60	1000	0.25	5	29.7	115	23	0.06 to 0.095
1N4755A	43	40.85- 45.15	6	70	1500	0.25	5	32.7	110	22	0.06 to 0.095
1N4756A	47	44.65- 49.35	5.5	80	1500	0.25	5	35.8	95	19	0.06 to 0.095
1N4757A	51	48.45- 53.55	5	95	1500	0.25	5	38.8	90	18	0.06 to 0.095
1N4758A	56	53.2- 58.8	4.5	110	2000	0.25	5	42.6	80	16	0.06 to 0.095
1N4759A	62	58.9- 65.1	4	125	2000	0.25	5	47.1	70	14	0.06 to 0.095
1N4760A	68	64.6- 71.4	3.7	150	2000	0.25	5	51.7	65	13	0.06 to 0.095
1N4761A	75	71.25- 78.75	3.3	175	2000	0.25	5	56	60	12	0.06 to 0.095

#### Note:

- 1) The dynamic resistance is derived from the 60 Hz AC voltage which results when an AC current having an RMS value equal to 10% of the Zener Current (I<sub>ZT</sub> or I<sub>ZK</sub>) is superimposed on I<sub>ZT</sub> or I<sub>ZK</sub>. Dynamic resistance is measured at two points to insure a sharp knee on the breakdown curve and to eliminate unstable units.
- 2) Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.
- 3) Tested with pulses tp = 20 ms.
- 4) The rating listed in the electrical characteristics table is maximum peak, non-repetitive, reverse surge current of 1/2 square wave or equivalent sine wave pulse of 1/120 second duration superimposed on the test current I<sub>ZT</sub>.



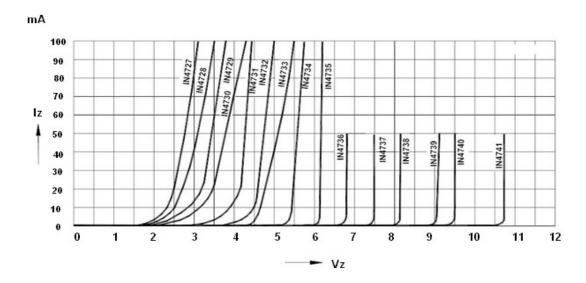
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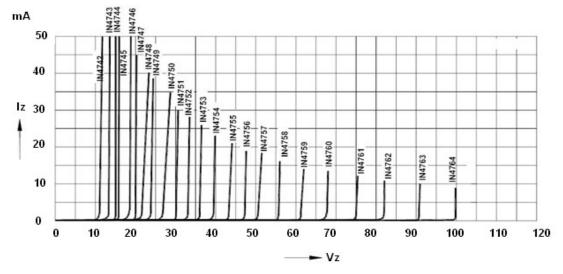


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# **Typical Characteristic Curves**

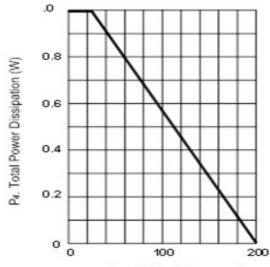
Breakdown Characterstics Tj=Constant (Pulsed)







# **Typical Characteristic Curves (continued...)**



TA, Ambient Temperature Fig. 1 Power Dissipation vs Ambient Temperature

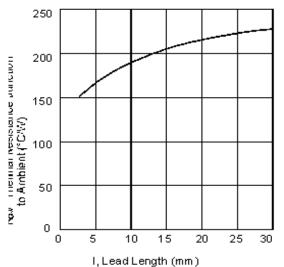
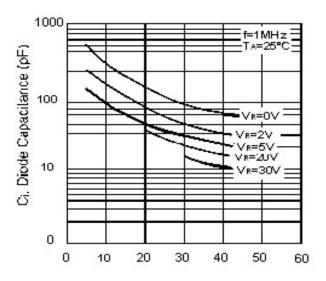


Fig. 2 Typical Thermal Resistance vs. Lead Length



Vz, Zener Voltage (V) Fig. 3 Junction Capacitance vs Zener Voltage

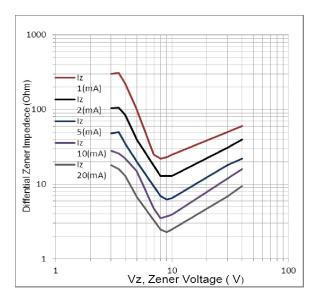
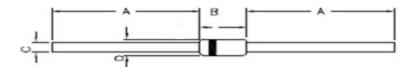


Fig.4 Typical Zener impedance vs Zener Voltage



# **Package Details**



**DO-41 PACKAGE DIMENSION** 

Package	DO-41			
Dimensions	Min	Max		
Α	25.4	-		
В	-	4.2		
С	-	Ф 0.7		
D	-	Ф2.8		

All dimensions are in mm.



# Recommended Product Storage Environment for Diode and Transistors

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying.
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

#### Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years, the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

## Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start. For this the following JEDEC table may be referred:

JEDEC MSL Level					
Level	Time	Condition			
1	Unlimited	< 30 °C / 85% RH			
2	1 Year	≤30 °C / 60% RH			
2a	4 Weeks	< 30 °C / 60% RH			
3	168 Hours	≤30 °C / 60% RH			
4	72 Hours	<30 °C / 60% RH			
5	48 Hours	≤30 °C / 60% RH			
5a	24 Hours	< 30 °C / 60% RH			
6	Time on Label(TOL)	≤30 °C / 60% RH			

Figure 1 Floor Life according to JEDEC MSL Level



## **Customer Notes**

## **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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